

# **Regulating Pulse Width Modulators**

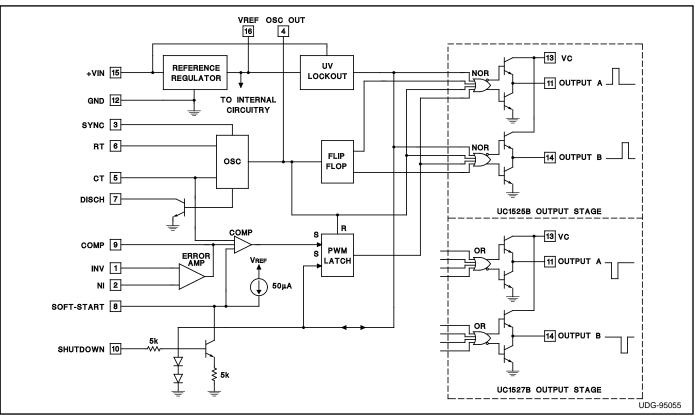
# FEATURES

- 8 to 35V Operation
- 5.1V Buried Zener Reference Trimmed to ±0.75%
- 100Hz to 500kHz Oscillator Range
- Separate Oscillator Sync Terminal
- Adjustable Deadtime Control
- Internal Soft-Start
- Pulse-by-Pulse Shutdown
- Input Undervoltage Lockout with Hysteresis
- Latching PWM to Prevent Multiple Pulses
- Dual Source/Sink Output Drivers
- Low Cross Conduction Output Stage
- Tighter Reference Specifications

#### **BLOCK DIAGRAM**

#### DESCRIPTION

The UC1525B/1527B series of pulse width modulator integrated circuits are designed to offer improved performance and lowered external parts count when used in designing all types of switching power supplies. The on-chip +5.1V buried zener reference is trimmed to ±0.75% and the input common-mode range of the error amplifier includes the reference voltage, eliminating external resistors. A sync input to the oscillator allows multiple units to be slaved or a single unit to be synchronized to an external system clock. A single resistor between the CT and the discharge terminals provide a wide range of dead time adjustment. These devices also feature built-in soft-start circuitry with only an external timing capacitor required. A shutdown terminal controls both the soft-start circuitry and the output stages, providing instantaneous turn off through the PWM latch with pulsed shutdown, as well as soft-start recycle with longer shutdown commands. These functions are also controlled by an undervoltage lockout which keeps the outputs off and the soft-start capacitor discharged for sub-normal input voltages. This lockout circuitry includes approximately 500mV of hysteresis for jitter-free operation. Another feature of these PWM circuits is a latch following the comparator. Once a PWM pulse has been terminated for any reason, the outputs will remain off for the duration of the period. The latch is reset with each clock pulse. The output stages are totem-pole designs capable of sourcing or sinking in excess of 200mA. The UC1525B output stage features NOR logic, giving a LOW output for an OFF state. The UC1527B utilizes OR logic which results in a HIGH output level when OFF.



### **ABSOLUTE MAXIMUM RATINGS**

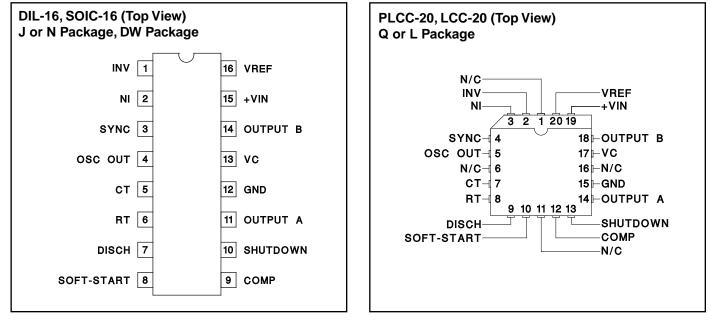
Supply Voltage, (+VIN)	+40V
Collector Supply Voltage (VC)	+40V
Logic Inputs	–0.3V to +5.5V
Analog Inputs	–0.3V to VIN
Output Current, Source or Sink	
Reference Output Current	
Oscillator Charging Current	5mA
Power Dissipation at TA = +25°C	1000mW
Power Dissipation at Tc = +25°C	
Operating Junction Temperature	–55°C to +150°C
Storage Temperature Range	–65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	+300°С
All currents are positive into, negative out of the	specified terminal.
Consult Packaging Section of Databook for the	ermal limitations
and considerations of packages.	

#### **CONNECTION DIAGRAMS**

#### **RECOMMENDED OPERATING CONDITIONS**

(Note 1)	(N	lote	1)	
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Input Voltage (+VIN)+8V to +35V
Collector Supply Voltage (VC)+4.5V to +35V
Sink/Source Load Current (steady state)
Sink/Source Load Current (peak)0 to 400mA
Reference Load Current
Oscillator Frequency Range
Oscillator Timing Resistor $\dots \dots \dots$
Oscillator Timing Capacitor
Dead Time Resistor Range $\dots \dots \dots$
Note 1: Range over which the device is functional and parame-
ter limits are guaranteed.



**ELECTRICAL CHARACTERISTICS** Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for the UC1525B and UC1527B;  $-40^{\circ}C$  to  $+85^{\circ}C$  for the UC2525B and UC2527B;  $0^{\circ}C$  to  $+70^{\circ}C$  for the UC3525B and UC3527B; +VIN = 20V,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	UC1525B/UC2525B UC1527B/UC2527B			UC3525B UC3527B			
		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Reference Section					-			
Output Voltage	$T_J = 25^{\circ}C$	5.062	5.10	5.138	5.036	5.10	5.164	V
Line Regulation	VIN = 8V to $35V$		5	10		5	10	mV
Load Regulation	I∟ = 0mA to 20mA		7	15		7	15	mV
Temperature Stability (Note 2)	Over Operating Range		10	50		10	50	mV
Total Output Variation	Line, Load, and Temperature	5.036		5.164	5.024		5.176	V
Short Circuit Current	VREF = 0, TJ =25°C		80	100		80	100	mA
Output Noise Voltage (Note 2)	$10Hz \le f \le 10kHz$ , TJ = $25^{\circ}C$		40	200		40	200	μVrms
Long Term Stability (Note 2)	TJ = 125°C, 1000 Hrs.		3	10		3	10	mV

**ELECTRICAL CHARACTERISTICS (cont.)** Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for the UC1525B and UC1527B;  $-40^{\circ}C$  to  $+85^{\circ}C$  for the UC2525B and UC2527B;  $0^{\circ}C$  to  $+70^{\circ}C$  for the UC3525B and UC3527B; +VIN = 20V,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	UC1525B/UC2525B UC1527B/UC2527B			UC3525B UC2527B			
		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Oscillator Section (Note 3)	•	-			•	•	1	
Initial Accuracy (Notes 2 & 3)	$T_J = 25^{\circ}C$		±2	±6		±2	±6	%
Voltage Stability (Notes 2 & 3)	VIN = 8V to $35V$		±0.3	±1		±1	±2	%
Temperature Stability (Note 2)	Over Operating Range		±3	±6		±3	±6	%
Minimum Frequency	$RT = 200k\Omega$ , $CT = 0.1\mu F$			120			120	Hz
Maximum Frequency	$RT = 2k\Omega$ , $CT = 470pF$	400			400			kHz
Current Mirror	IRT = 2mA	1.7	2.0	2.2	1.7	2.0	2.2	mA
Clock Amplitude (Notes 2 & 3)		3.0	3.5		3.0	3.5		V
Clock Width (Notes 2 & 3)	$T_J = 25^{\circ}C$	0.3	0.5	1.0	0.3	0.5	1.0	μs
Sync Threshold		1.2	2.0	2.8	1.2	2.0	2.8	V
Sync Input Current	Sync Voltage = 3.5V		1.0	2.5		1.0	2.5	mA
Error Amplifier Section (VCM = 5.1)	/)							
Input Offset Voltage			0.5	5		2	10	mV
Input Bias Current			1	10		1	10	μA
Input Offset Current				1			1	μA
DC Open Loop Gain	$RL \ge 10 Meg\Omega$	60	75		60	75		dB
Gain-Bandwidth Product (Note 2)	$Av = 0dB, T_J = 25^{\circ}C$	1	2		1	2		MHz
Output Low Level			0.2	0.5		0.2	0.5	V
Output High Level		3.8	5.6		3.8	5.6		V
Common Mode Rejection	Vcm = 1.5V to 5.2V	60	75		60	75		dB
Supply Voltage Rejection	VIN = 8V to 35V	50	60		50	60		dB
PWM Comparator	•			•	•	•	•	
Minimum Duty Cycle				0			0	%
Maximum Duty Cycle		45	49		45	49		%
Input Threshold (Note 3)	Zero Duty Cycle	0.7	0.9		0.7	0.9		V
Input Threshold (Note3)	Maximum Duty Cycle		3.3	3.6		3.3	3.6	V
Input Bias Current (Note 2)			0.05	1.0		0.05	1.0	μA
Shutdown Section								
Soft Start Current	Vshutdown = 0V, Vsoftstart = 0V	25	50	80	25	50	80	μA
Soft Start Low Level	VSHUTDOWN = 2.5V		0.4	0.7		0.4	0.7	V
Shutdown Threshold	To outputs, VSOFTSTART = 5.1V, TJ =25°C	0.6	0.8	1.0	0.6	0.8	1.0	V
Shutdown Input Current	VSHUTDOWN = 2.5V		0.4	1.0		0.4	1.0	mA
Shutdown Delay (Note 2)	VSHUTDOWN = 2.5V, TJ = 25°C	1	0.2	0.5		0.2	0.5	μs
Output Drivers (Each Output) (VC =	· · · · · · · · · · · · · · · · · · ·	•						• •
Output Low Level	ISINK = 20mA		0.2	0.4		0.2	0.4	V
	Isink = 100mA		1.0	2.0		1.0	2.0	V
Output HIgh Level	ISOURCE = 20mA	18	19		18	19		V
	ISOURCE = 100mA	17	18		17	18		V
Undervoltage Lockout	VCOMP and VSOFTSTART = High	6	7	8	6	7	8	V
Collector Leakage	VC = 35V			200			200	μA

**ELECTRICAL CHARACTERISTICS (cont.)** Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for the UC1525B and UC1527B;  $-40^{\circ}C$  to  $+85^{\circ}C$  for the UC2525B and UC2527B;  $0^{\circ}C$  to  $+70^{\circ}C$  for the UC3525B and UC3527B; +VIN = 20V,  $T_A = T_J$ .

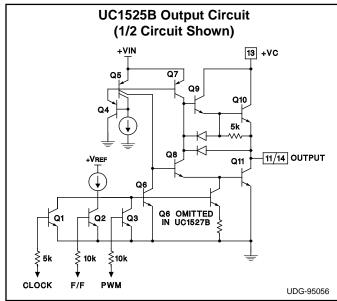
PARAMETER		UC1525B/UC2525B UC1527B/UC2527B			UC3525B UC2527B			
	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Output Drivers (Each Output) (	VC = 20V) (cont.)							
Rise Time (Note 2)	C∟ = 1nF, TJ = 25°C		100	600		100	600	ns
Fall Time (Note 2)	C∟ = 1nF, TJ = 25°C		50	300		50	300	ns
Cross conduction charge	Per cycle, TJ = 25°C		30			30		nc
Total Standby Current		•			•			
Supply Current	VIN = 35V		14	20		14	20	mA

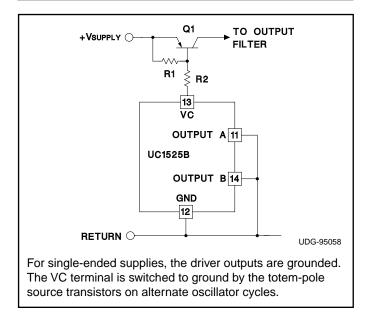
Note 2: Guaranteed by design. Not 100% tested in production.

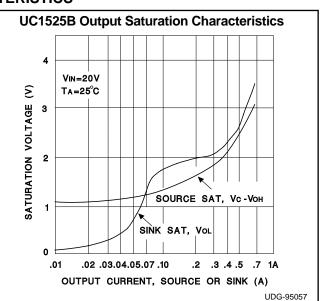
Note 3. Tested at fosc= 40kHz ( $R\tau = 3.6\Omega$ ,  $C\tau = 0.01\mu F$ ,  $RD = 0\Omega$ ). Approximate oscillator frequency is defined by:

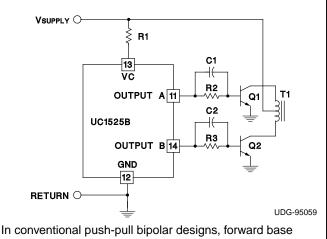
$$f = \frac{1}{CT \bullet (0.7 \bullet RT + 3RD)}$$

#### PRINCIPLES OF OPERATION AND TYPICAL CHARACTERISTICS

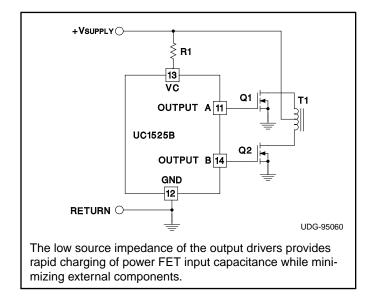








drive is controlled by R1-R3. Rapid turn-off times for the power devices are achieved with speed-up capacitors C, and C2.

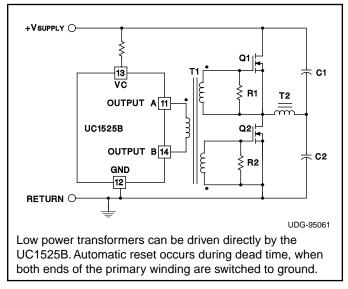


# PRINCIPLES OF OPERATION AND TYPICAL CHARACTERISTICS

#### Shutdown Options (See Block Diagram)

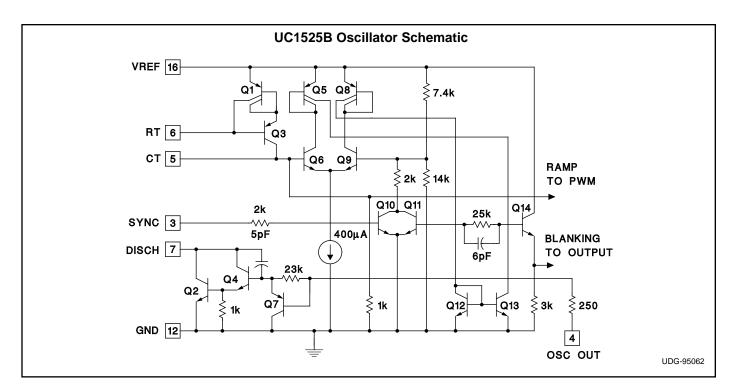
Since both the compensation and soft-start terminals (Pins 9 and 8) have current source pull-ups, either can readily accept a pull-down signal which only has to sink a maximum of  $100\mu$ A to turn off the outputs. This is subject to the added requirement of discharging whatever external capacitance may be attached to these pins.

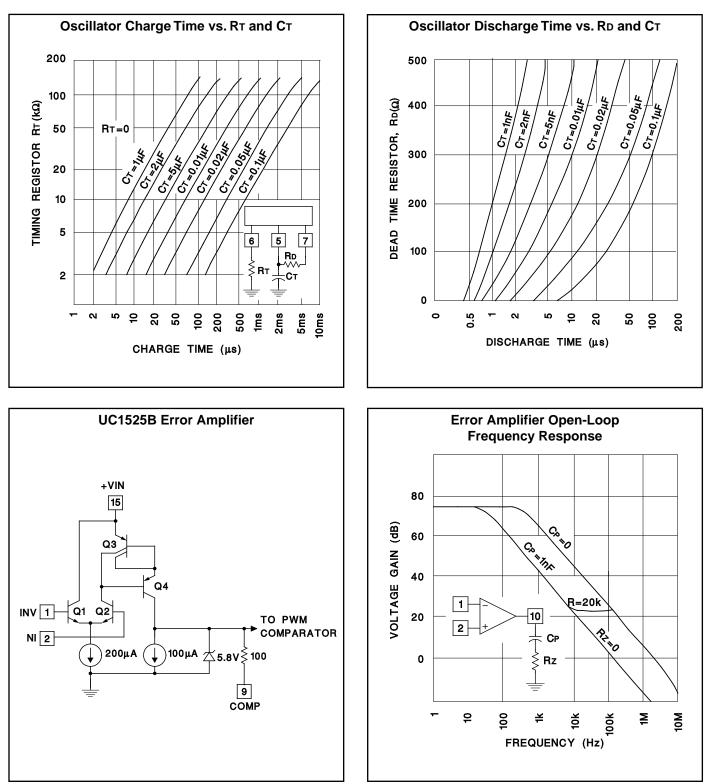
An alternate approach is the use of the shutdown circuitry of Pin 10 which has been improved to enhance the available shutdown options. Activating this circuit by



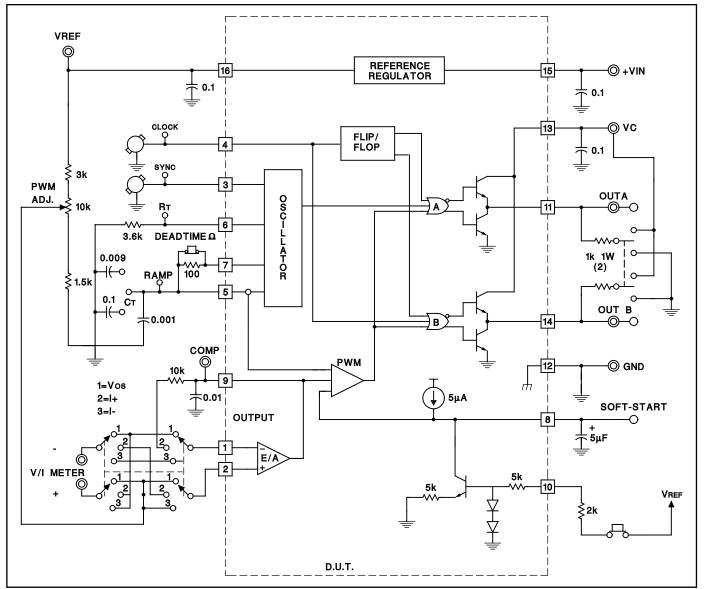
applying a positive signal on Pin 10 performs two functions: the PWM latch is immediately set providing the fastest turn-off signal to the external soft-start capacitor. If the shutdown command is short, the PWM signal is terminated without significant discharge of the soft-start capacitor, thus, allowing, for example, a convenient implementation of pulse-by-pulse current limiting. Holding Pin 10 high for a longer duration, however, will ultimately discharge this external capacitor, recycling slow turn-on upon release.

Pin 10 should not be left floating as noise pickup could conceivably interrupt normal operation.





#### LAB TEST FIXTURE



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